

Features

- Split Gate Trench MOSFET Technology
- Low Thermal Resistance
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 40°C/W Junction to Ambient

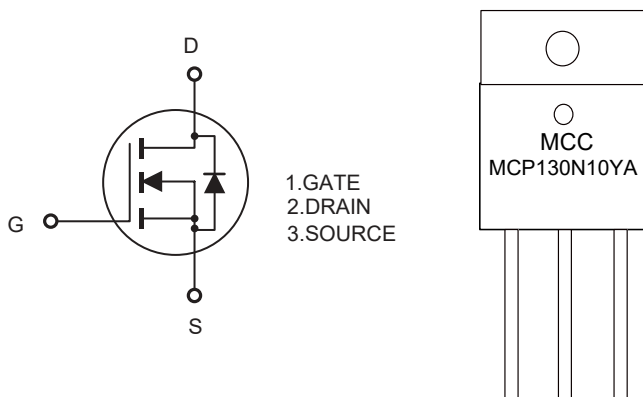
Parameter	Symbol	Rating	Unit
Drain -Source Voltage	V_{DS}	100	V
Gate -Source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I_D	$T_C=25^\circ\text{C}$	130
		$T_C=100^\circ\text{C}$	82
Drain Current-Pulse ^(Note2)	I_{DM}	520	A
Power Dissipation	P_D	310	W
Single Pulsed Avalanche Energy ^(Note3)	E_{AS}	552	mJ

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

2. Pulse Width Limited by Maximum Junction Temperature.

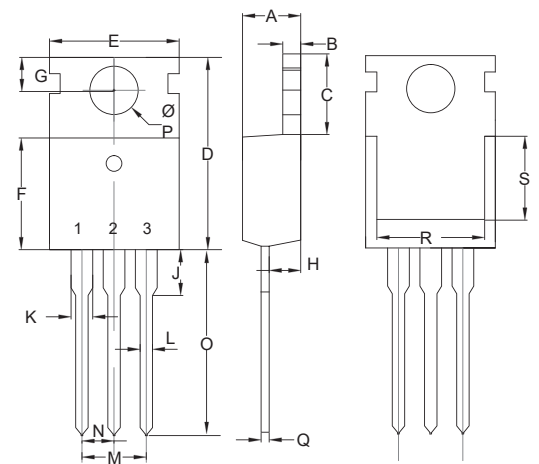
3. L=2mH, IAS=23.5A, $V_{DD}=50\text{V}$, $V_{GS}=10\text{V}$, $R_G=25\Omega$, Starting $T_J=25^\circ\text{C}$

Internal Structure and Marking Code



N-Channel Enhancement Mode Field Effect Transistor

TO-220AB(H)



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.172	0.188	4.37	4.77	
B	0.049	0.057	1.25	1.45	
C	0.246	0.270	6.25	6.85	
D	0.594	0.634	15.10	16.10	
E	0.382	0.406	9.70	10.30	
F	0.346	0.370	8.80	9.40	
G	0.102	0.118	2.60	3.00	
H	0.087	0.102	2.20	2.60	
J	-----	0.134	-----	3.40	
K	0.046	0.058	1.17	1.47	
L	0.028	0.037	0.70	0.95	
M	0.200		5.08		TYP.
N	0.100		2.54		TYP.
O	0.502	0.543	12.75	13.80	
P	0.134	0.150	3.40	3.80	Φ
Q	0.016	0.026	0.40	0.65	
R	0.276	-----	7.00	-----	
S	0.217	-----	5.50	-----	

Electrical Characteristics @ 25°C (Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	100			V
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=100V, V_{GS}=0V, T_J=25^\circ C$			1	μA
		$V_{DS}=100V, V_{GS}=0V, T_J=150^\circ C$			100	
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	2.8	4	V
Drain-Source On-Resistance ^(Note4)	$R_{DS(on)}$	$V_{GS}=10V, I_D=65A$		4.5	5.5	m Ω
		$V_{DS}=10V, I_D=20A$		4.5	5.5	
Gate resistance	R_G	f=1MHz, Open drain		0.8		Ω
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=50V, V_{GS}=0V, f=1MHz$		4500		μF
Output Capacitance	C_{oss}			1700		
Reverse Transfer Capacitance	C_{rss}			25		
Total Gate Charge	Q_g	$V_{DD}=50V, V_{GS}=10V, I_D=65A$		62		nC
Gate-Source Charge	Q_{gs}			16		
Gate-Drain Charge	Q_{gd}			14		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DD}=50V, I_D=65A, R_G=2.2\Omega$		20		ns
Turn-On Rise Time	t_r			82		
Turn-Off Delay Time	$t_{d(off)}$			30		
Turn-Off Fall Time	t_f			7		
Drain-Source Body Diode Characteristics						
Body Diode Voltage	V_{SD}	$T_J=25^\circ C, I_{SD}=65A, V_{GS}=0V$		0.9	1.2	V
Reverse Recovery Time	t_{rr}	$I_F=65A, di/dt=600A/\mu s$		38		ns
Reverse Recovery Charge	Q_{rr}			175		μC
Diode Forward Current	I_s	$V_{GS} < V_{th}$			130	A
Pulsed Source Current	I_{sp}				440	

Notes:

4. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.

Curve Characteristics

Fig. 1 - Typical Output Characteristics

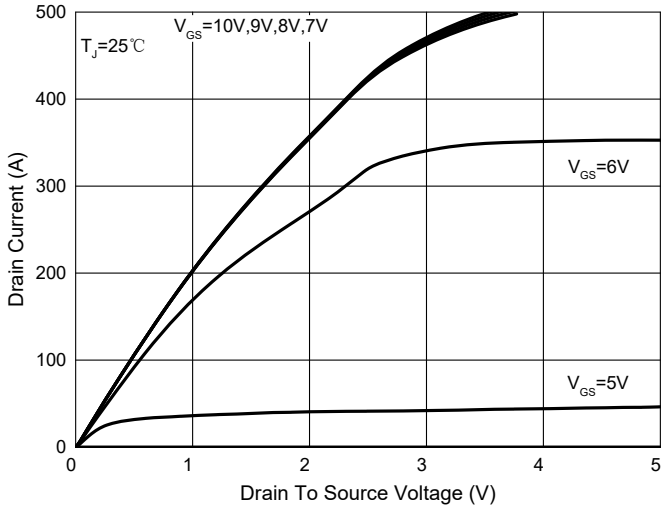


Fig. 2 - Transfer Characteristics

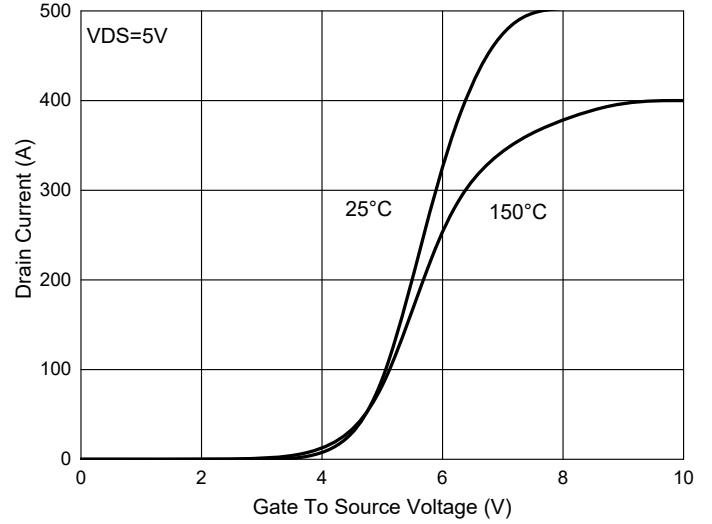


Fig. 3 - $R_{DS(ON)} - I_D$

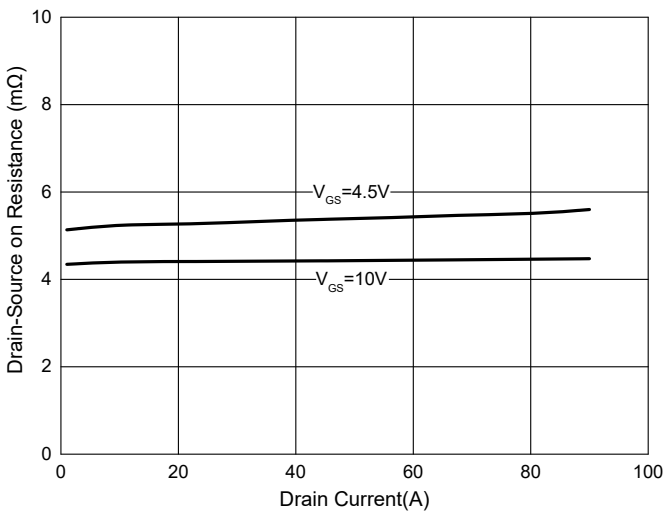


Fig. 4- $I_S - V_{SD}$

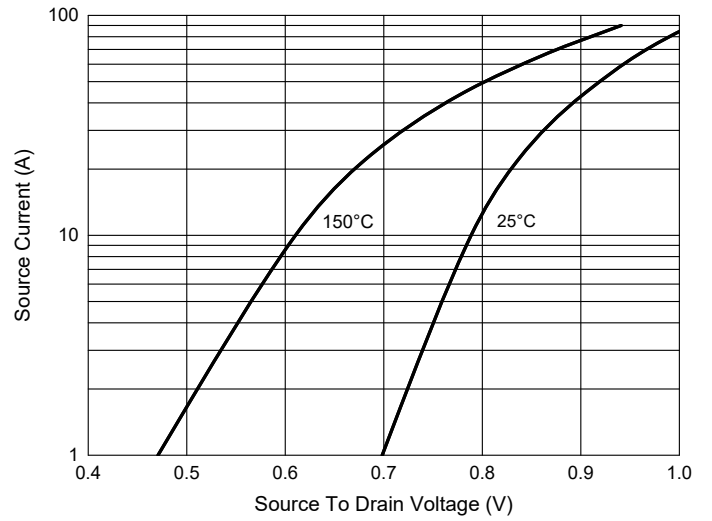


Fig. 5 - Normalized On Resistance Characteristics

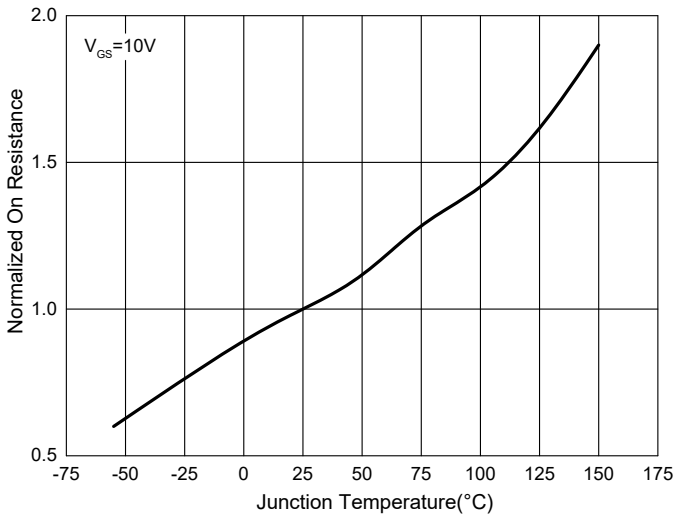
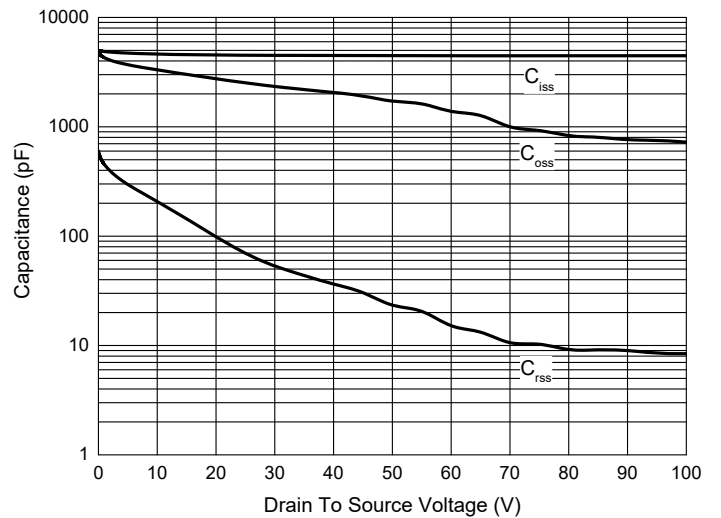


Fig. 6 - Capacitance Characteristics



Curve Characteristics

Fig. 7- Gate Charge

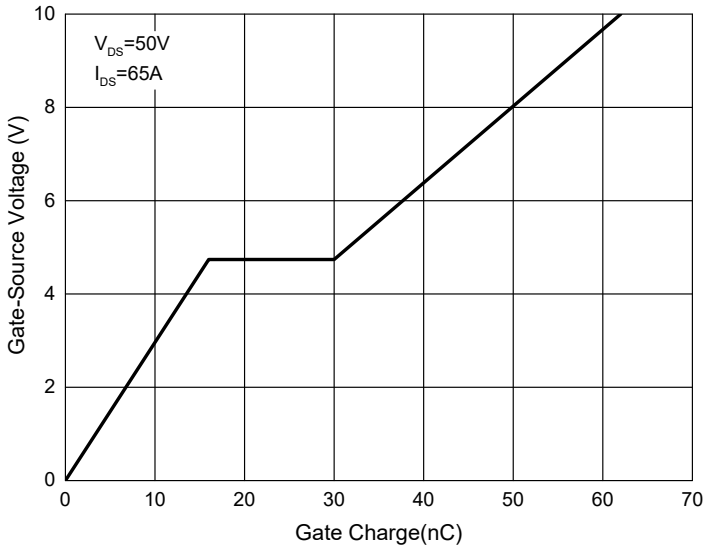


Fig. 8 - $R_{DS(ON)} - V_{GS}$

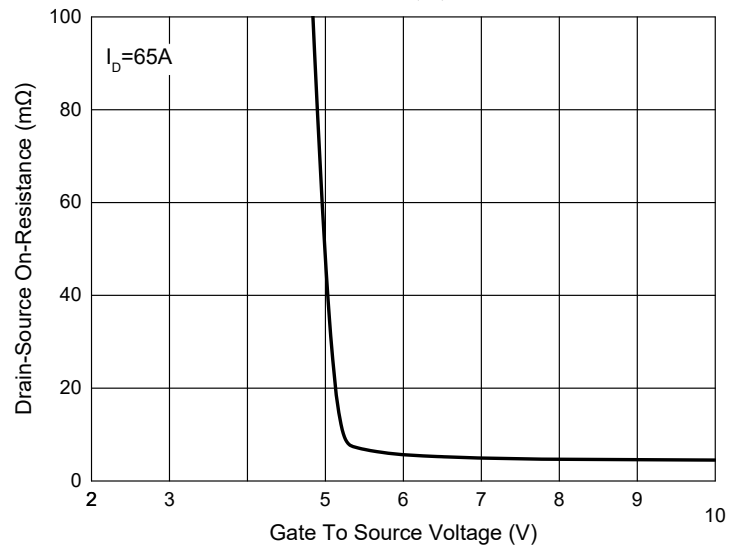


Fig. 9- Safe Operation Area

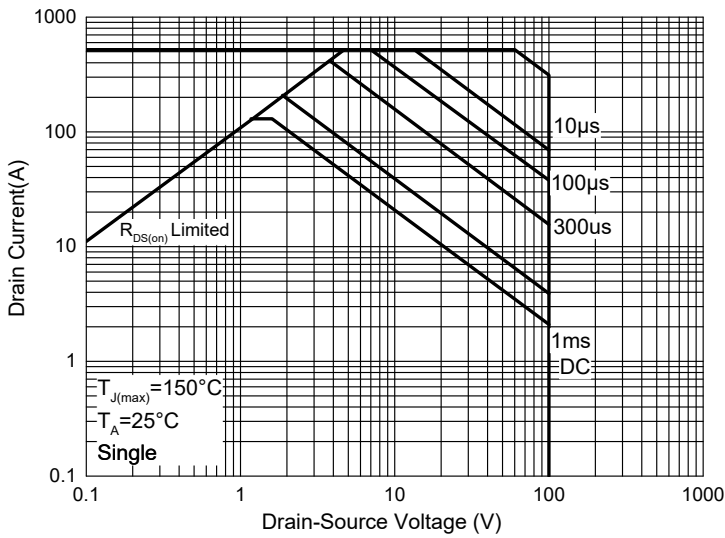
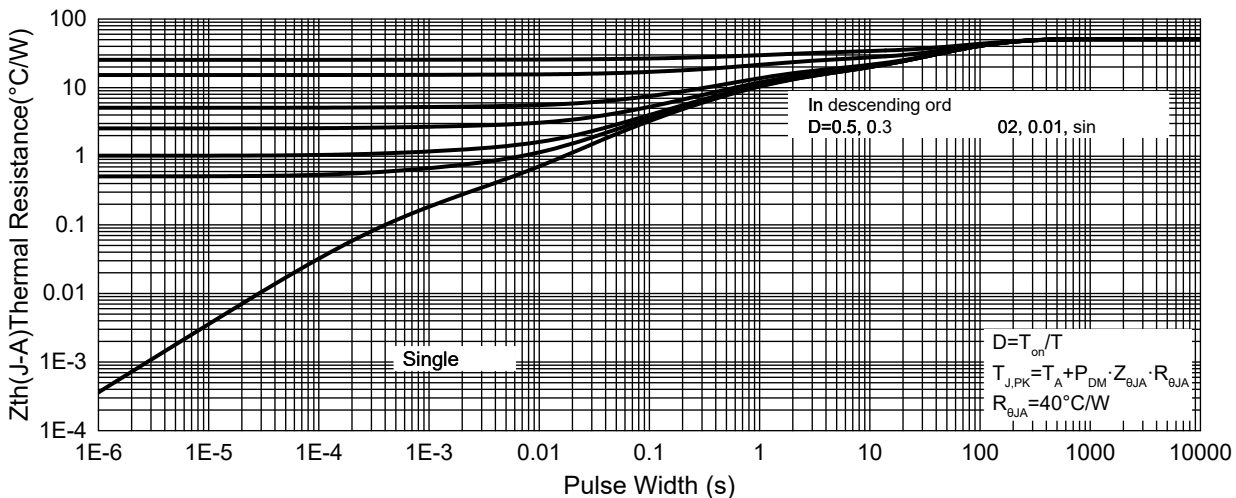


Fig. 10 - Maximum Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-BP	Bulk:50pcs/Tube, 1Kpcs/Box,5Kpcs/Carton

IMPORTANT NOTICE

Micro Commercial Components Corp. reserves the right to make changes without further notice to any product herein to make corrections, modifications , enhancements , improvements , or other changes . **Micro Commercial Components Corp** . does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights ,nor the rights of others . The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp** . and all the companies whose products are represented on our website, harmless against all damages. **Micro Commercial Components Corp**. products are sold subject to the general terms and conditions of commercial sale, as published at <https://www.mccsemi.com/Home/TermsAndConditions>.

LIFE SUPPORT

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

CUSTOMER AWARENESS

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. **MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources.** MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.